NSN 5961-01-210-8893

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-210-8893 **Inclosure Material:** Metal **Overall Length:** 0.150 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.230 inches **Internal Configuration:** Field effect-dual gate **Electrode Internally-electrically Connected To Case:** Drain **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 drain to source voltage and 60.0 drain to gate voltage **Current Rating Per Characteristic:** 0.90 amperes source cutoff current of standard range **Power Rating Per Characteristic:** 1.25 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**